Excitation dependent recombination studies on SnO$_2$/$\text{TiO}_2$ electrospun nanofibers†

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Poly(vinyl acetate) (PVAc)/TiO$_2$ nanofibers, PVAc/SnO$_2$ nanoribbons and PVAc/SnO$_2$–TiO$_2$ nanoribbons were produced via electrospinning. TiO$_2$ nanofibers and SnO$_2$ nanoribbons were obtained by removal of the polymeric matrix (PVAc) after calcination at 450 °C. Interestingly, PVAc/SnO$_2$–TiO$_2$ nanoribbons were transformed into SnO$_2$–TiO$_2$ nanofibers after calcination under the similar conditions. Fiber morphology and elemental mapping confirmed through SEM and TEM microscope techniques respectively. The X-ray diffraction measurements suggested the presence of anatase TiO$_2$ and rutile SnO$_2$ and both were present in the SnO$_2$–TiO$_2$ mixed system. Systematic photoluminescence studies were performed on the electrospun nanostructures at different excitation wavelengths ($\lambda_{\text{ex1}} = 325$, $\lambda_{\text{ex2}} = 330$, $\lambda_{\text{ex3}} = 350$, $\lambda_{\text{ex4}} = 397$ and $\lambda_{\text{ex5}} = 540$ nm). We emphasize that the defects in the SnO$_2$–TiO$_2$ based on the defect levels present in TiO$_2$ and SnO$_2$ and anticipate that these defect levels may have great potential in understanding and characterizing various semiconducting nanostructures.

Introduction

1D nanostructures via electrospinning have attracted significant attention due to the fact that their distinctive surface and quantum effects can influence the functionality and performance in nanodevices. Among semiconductors, SnO$_2$ and TiO$_2$ have evoked considerable attention due to their potential applications in optoelectronic devices, despite the anatase phase of TiO$_2$ being more photoactive. It has been found that a combination of SnO$_2$ and TiO$_2$ gives the most significant sensing and photocatalytic applications. In addition, SnO$_2$ and TiO$_2$ have a large bandgap (3.2 eV for anatase TiO$_2$ and 3.6 eV for SnO$_2$) which ensures that the electrons within the conduction band (CB) have a strong reducing ability and the holes in the valence band (VB) have a strong oxidizing ability. The impurities or defect states induced by the synthesis methods can form deep energy levels (which act as trapping centres) or shallow energy levels (which act as donors). These shallow trap levels (lying in the bandgap) act as carrier traps in competition with the fast carrier recombination in the bulk during photoexcitation, which enhances the photocatalytic activity of the nanostructures. On the other hand, Zhu et al. reported that by considering chemical potentials, the deep trap levels exhibited reduced photocatalytic activities. Titania is a highly ionic lattice with a VB composed of oxygen 2p orbitals (the wave functions are considerably localized on the O$^{2-}$ lattice site), while the CB consists mostly of excited states of Ti$^{4+}$. The width of the VB in Ti$^{2+}$ 2p is about 16 eV and the breadth of the CB in Ti$^{4+}$ 3d is about 27 eV.

Optical spectroscopy studies have been used extensively for the detection of CB electrons, trapped electrons, holes, and transition energy levels. Ghosh et al. reported that the rutile TiO$_2$ single crystal consists of at least eight shallow trap levels (<1 eV below the CB). Later, the midgap energy related defects were identified from surface or bulk trap state luminescence either by surface modification of TiO$_2$ nanoparticles with a loading of platinum or by treatment with TiCl$_4$. Ariga et al. demonstrated that photo-oxidation on the TiO$_2$ (001) surface has a threshold energy between 2.1 and 2.3 eV (539–590 nm), which is apparently much lower than that of the bandgap energy (3.0–3.2 eV). The two defect related bands were observed in titanate nanostructures (at 463 and 533 nm) and assigned to carrier trapping at defect centers. On the other hand, the optical properties of SnO$_2$ are of great importance because of the even parity symmetry which precludes from the band-edge radiation transition. Upon reducing the dimensionality of the SnO$_2$ crystals, the wave function symmetry can be broken due to quantum confinement and hence the dipole forbidden selection rule can be relieved, giving rise to the free exciton emission. The luminescence would be dependent on the shape of the nanostructures such as the fishbone-like nanoribbons of SnO$_2$ that exhibit green emission. Luo et al. performed temperature dependent PL on SnO$_2$ nanowires and nanobelts where two bands centered at 470 nm and 560 nm were observed with the intensity of the former band being strongly dependent.

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on temperature. Blue/violet emission was also reported for different shapes of SnO$_2$ nanocafelows, nanoblades, and other types of nanostructures. Kar et al. reported the morphology dependent luminescence for SnO$_2$ nanorods and nanoparticles. The exciton binding energy of SnO$_2$ is as large as 130 meV, which envisages efficient exciton emission at room temperature and even at higher temperatures. Kılıç and Zunger observed five intrinsic defects coexisting in SnO$_2$, which are oxygen vacancies (V$_{O}$), tin vacancies (V$_{Sn}$), tin antisite defects (Sn$_{O}$), oxygen interstitial sites (O$_i$) and tin interstitial sites (S$_{ni}$). S$_{ni}$ and V$_{O}$ are the predominant defect structures in SnO$_2$ due to the multivalency of tin. These defect structures can produce shallow donor levels that cause n-type conduction which originates from the V$_{O}$, where the V$_{O}$ can capture electrons which leads to singly ionized vacancies (V$_{O}^+$) or doubly ionized vacancies (V$_{O}^{2+}$). However, there are inadequate reports on electrosprun SnO$_2$/TiO$_2$ nanofibers with excitation dependent emission spectra analysis.

In the present study, the systematic excitation dependent photoluminescence (PL) on TiO$_2$, SnO$_2$ and SnO$_2$–TiO$_2$ electrosprun nanofibers are conducted. The PL emission peaks are dependent on the bandgap and surface defects. The plausible band alignment is also proposed and discussed with respect to the excitation energy.

**Experimental**

**Materials**

All the chemicals were purchased and used without further purification: titanium(n) isopropoxide (TIP, 97%, Sigma-Aldrich); tin(n) chloride (SnCl$_4$, 99%, Sigma-Aldrich); polyvinyl acetate (M$_w$: 350 000); methanol (99%, Sigma-Aldrich); and glacial acetic acid (100%, Merck).

**Synthesis of the nanostructures**

The preparation of nanostructures via electrospinning is a well-known technology. The polymer solutions were prepared by dissolving 1.2 g of PVAc in 10 mL of methanol and stirring for ~3 h. For the TiO$_2$ preparation, 2 mL of glacial acetic acid was added to the polymer solution, followed by 1 mL TIP which was then subjected to stirring for ~6 h to obtain a clear and homogeneous solution. For the SnO$_2$ synthesis, 0.5 mL of SnCl$_4$ was added to the polymer solution (PVAc) and subjected to stirring for ~6 h. Whereas for the SnO$_2$–TiO$_2$ solution, 2 mL of glacial acetic acid, 1 mL TIP and 0.5 mL of SnCl$_4$ were added to the polymer solution (PVAc) and subjected to ~6 h of stirring.

The solution was taken in a 10 mL syringe (21 G 1/2 needle) and was placed in a commercially available electrospinning machine Nanoweb (Electrospin 100) for the preparation of the nanofibers. The flow rate was adjusted to 25 mL m$^{-1}$ with a syringe pump (KD Scientific, KDS 101), the distance between the two electrodes (tip of the needle to collector) was maintained at 8 cm, and the applied voltage between the rotating drum collector (with a speed of 200 rpm) and the tip of the needle was 15 kV. The electrospun PVAc/TiO$_2$ nanofibers, PVAc/SnO$_2$ nanoribbons and PVAc/SnO$_2$–TiO$_2$ nanoribbons were then subjected to calcination at 450 °C for about 3 h. After calcination the samples are referred to in a short form as TNF, SNR and STNF, respectively.

**Characterization**

Thermal analysis was performed on the nanostructures using a thermogravimetric analyser (TGA, Q500, TA Instruments) in the range of room temperature ($T_R$) to 700 °C in a nitrogen atmosphere. The morphologies of the microstructures and nanostructures were observed by scanning electron microscopy (SEM, FEI-Quanta 200 FEG). Approximately 5 nm of Au/Pd was sputtered on the samples before they were subjected to SEM scanning. The nanofibers were examined using transmission electron microscopy (TEM, FEI-Tecnai G2 F30). The samples were dispersed in ethanol and a tiny drop was dried on a holey carbon coated TEM grid and analysed with energy dispersive X-ray spectroscopy (EDX) for elemental analysis. The crystal structures of the nanofibers were characterized using a PANalytical X’Pert Pro multipurpose X-ray diffractometer (XRD) in the range of 2$\theta$ = 20–80° with CuKz (1.5418 Å) radiation. UV-vis absorbance spectroscopy of the nanostructures was performed using a UV-vis spectrometer (VARIAN, Cary 5000) by taking nearly 1–5 mg of dispersion in a quartz cuvette. PL measurements were performed on the fibers as free standing flakes in the PL spectrometer (Jobin Yvon, FL-1057 TCSPC) at different excitation wavelengths ($\lambda_{ex}$ = 325, 350, 380, 420, 490 nm). The XRD peaks and PL emission peaks were deconvoluted with a Lorentz and Gauss fitting respectively, with Origin 8.5 where it was necessary.

**Results and discussion**

**Surface morphology**

The surface morphology of the nanostructures was observed by SEM and is shown in Fig. 1. The as-spun nanostructures of PVAc/TiO$_2$, PVAc/SnO$_2$, and PVAc/SnO$_2$–TiO$_2$ exhibit fiber (Fig. 1a), ribbon (Fig. 1c) and ribbon (Fig. 1e) like structures and after calcination they are denoted as TNF, SNR and STNF, respectively. However, all these nanostructures are smooth and bead-free. That is to say, the charges (viscoelastic force and electrostatic repulsion) between the precursor solutions were successfully balanced by controlling the process parameters (humidity, flow rate, substrate rotation speed and high voltage) to suppress the influence of surface tension which drives the bead formation.

The calcination of the as-spun nanostructures was carried out at 450 °C. The successful removal of the polymeric part from the PVAc/TiO$_2$, PVAc/SnO$_2$ and PVAc/SnO$_2$–TiO$_2$ nanostructures was first confirmed by TGA studies. The main weight loss occurs between 100 and 400 °C due to the decomposition of the polymeric matrix (PVAc) and organic content of the precursors present in the as-spun nanostructures (Fig. SI-1f). Interestingly, after calcination, the morphology of TNF (Fig. 1b) and SNR (Fig. 1d) remains unchanged, whereas PVAc/SnO$_2$–TiO$_2$ is converted to fiber shaped STNF (Fig. 1f) and the fibers are uniform throughout their lengths. The decrease in dimensions after
calcination and the rougher surface is due to the loss of organic substances and crystallization during the thermal treatment.\textsuperscript{37} The average dimensions of the nanostructures with their standard deviation are presented (see Fig. SI-2 and Table SI-1†) for a clear estimation. The possible mechanism for the transformation of ribbons into fibers is most likely to be ‘wrapping of sheet’ because of mechanical stress\textsuperscript{38} arising during the crystallization/dissolution. Generally when a surface experiences an asymmetrical stress the excess surface energy results in wrapping or scrolling.\textsuperscript{39} Ma \textit{et al.}\textsuperscript{40} evidenced the direct rolling of nanosheets into nanotubes of single layered titanates along the (010) axis. In single layered nanosheets, the interaction energy between atoms mostly lies in the same layer hence the sheets grow at the edges of the individual layers, rather than creating a new layer,\textsuperscript{40,41} \textit{i.e.} the interaction energy between the atoms of inter-layers was less than that between intra-layer atoms, which differs as much as 500 times. Apart from this, in the presence of an asymmetrical chemical environment\textsuperscript{39} the excess surface energy causes bending and/or curving. Therefore the gain in surface energy is sufficient to convert nanoribbons into nanofibers.

From the TEM image presented in Fig. 2a it is evident that the nanostructures of STNF are composed of crystalline nanoparticles along the length of the fiber. Fig. 2b, at a higher magnification, depicts the grains of the nanofiber. The lattice resolved image is shown in Fig. SI-3† where one can identify the lattice patterns of TiO\textsubscript{2} and SnO\textsubscript{2}. The EDX spectrum in Fig. 2c confirms the presence of Ti, Sn and O components in the STNF fibers. While the inset of Fig. 2c represents the elemental mapping of TEM micrographs, which confirms that the Ti, Sn and O spatial distributions overlap in the selected region.

\section*{Crystal structure}

XRD patterns of the nanofibrous structures are shown in Fig. 3. The diffraction peaks related to TNF are indexed and confirmed to be the anatase (A) phase according to the JCPDS file no. 21-1272, as presented in Fig. 3a. There are no indications of the peaks related to impurities or other phases like rutile/brookite within the detection limits of the XRD. The anatase phase is still predominant at 450 °C while a complete transformation was observed to occur at 750 °C from the literature.\textsuperscript{42,43} In the case of SNR the peaks are indexed according to the JCPDS file no. 72-1147 confirming the rutile SnO\textsubscript{2} phase which is consistent with the literature.\textsuperscript{44–46} The XRD pattern related to STNF is presented in Fig. 3a. It is important to note that the presence of SnO\textsubscript{2} hinders the growth of TiO\textsubscript{2} linkage which results in the formation of smaller crystallites (see Table 1). This is confirmed by the broadened XRD peaks with respect to TNF and SNR. That is why there are no well resolved peaks identified for STNF. As shown in Fig. 3b, the corresponding peaks are identified. From Fig. 3b, the rutile phase ratio is higher than SnO\textsubscript{2} and anatase TiO\textsubscript{2}. Competition between the multiple phase elements might lead to a dominate rutile phase in STNF. Since both of these systems are tetragonal crystals, the lattice parameters and d-spacing values are determined using the equation given in ref. 47.

![Fig. 1](image-url)  
**Fig. 1** SEM images of the as-spun nanostructures of (a) PVAc/TiO\textsubscript{2}, (c) PVAc/SnO\textsubscript{2}, (e) PVAc/SnO\textsubscript{2}−TiO\textsubscript{2} and after calcination (b) TNF, (d) SNR and (f) STNF at 450 °C.

![Fig. 2](image-url)  
**Fig. 2** (a) TEM image of a single nanofiber composed of STNF, (b) a higher magnification TEM and (c) EDX spectrum and elemental mapping images of TEM micrographs for STNF.
From Fig. 4, the full width at half maximum (FWHM) of the diffraction peaks are obtained. The FWHM values and the crystallite sizes ($d_{hkl}$) were calculated through the Debye–Scherrer formula.\(^{48}\) The calculated crystallite sizes of individual TNF, SNR and STNF are presented in Table 1. The crystallite sizes of STNF are smaller than those of the individual systems. However, by changing the calcination environment to either O\(_2\) or under vacuum does not cause any influence on the crystalline sizes.\(^{48}\) It is noted that at all Bragg reflections assigned to the tetragonal phase, a shift to slightly higher 2\(\theta\) values from the STNF system is seen. This might be due to the lattice compression/expansion during calcination. Furthermore, the surface area ($S_a$) of the nanostructures is also calculated by eqn (1):\(^{50,51}\)

$$S_a = \frac{6}{d_{hkl} \times \rho} \quad (1)$$

where the molecular density ($\rho$) is obtained from eqn (2):

$$\rho = \frac{nM}{NV} \quad (2)$$

where $n$ represents the number of formula units per unit cell (4 for anatase and 2 for SnO\(_2\)), $M$ is the molecular weight, $N$ is Avogadro’s number, and $V$ is the volume of the unit cell. The higher the surface area is, the lower the activation energy is, which precludes the phase transformation below a certain temperature.\(^{50}\)

Two types of doping, viz. (a) interstitial and (b) substitutional, can be expected depending on the electronegativity and ionic radius. For the first one, if the electronegativity (on the Pauling scale) of Sn\(^{4+}\) is closer to that of Ti\(^{4+}\) and the ionic radius (in Å) of Sn\(^{4+}\) is smaller than that of Ti\(^{4+}\), then the lattice spacing will become larger. Then the doping ion will enter into the crystal cell of the oxide. While for the second one, if the electronegativity and ionic radius of the doping metal ions match those of the lattice metal ions in oxides, the doping metal ion will substitute itself for the lattice metal ion in the doping reactive process.\(^{52}\) Since the difference in electronegativity of Sn\(^{4+}\) (1.96) and Ti\(^{4+}\) (1.54) results in a change in the volume of STNF, it could be expected that Sn\(^{4+}\) will replace Ti\(^{4+}\) in the lattice and occupy the Ti\(^{3+}\) positions by substitutional doping. Therefore, the volume of the unit cell (see Table 1) of STNF is moderately between that of TNF and SNR. In addition, the ionic radius of Sn\(^{4+}\) (0.71 Å)\(^{53}\) is larger than that of the Ti\(^{4+}\) (0.68 Å)\(^{53}\) ion, which will induce lattice distortions in STNF. From Table 1, the volume of the unit cell is very consistent, which indicates that the lattice would relax as Sn\(^{4+}\) ions with a larger ionic radius are substituted for Ti\(^{4+}\) in TiO\(_2\).

![Fig. 3 X-ray diffraction profiles of (a) TNF, SNR and STNF and (b) STNF decomposed using Lorentz fitting. XRD patterns are indexed according to JCPDS file no. 21-1272 and JCPDS file no. 72-1147 for anatase TiO\(_2\) and SnO\(_2\) respectively.](image)

Table 1 From the XRD data of TNF, SNR and STNF, where a, b, and c, are the lattice parameters, $V$, is the volume of the cell, $S_a$ is the surface area, and $d$ is the crystallite size.

<table>
<thead>
<tr>
<th>Lattice parameters (Å)</th>
<th>$V = \frac{a^2 \times c}{\sqrt{2}}$ (Å$^3$)</th>
<th>$V$ per molecule (Å$^3$)</th>
<th>d (nm)</th>
<th>$S_a$ (m$^2$ g$^{-1}$)</th>
<th>Peak positions</th>
</tr>
</thead>
<tbody>
<tr>
<td>TNF-A</td>
<td>3.7595 9.4189 2.505</td>
<td>133.125 33.281</td>
<td>11.14</td>
<td>135.19</td>
<td></td>
</tr>
<tr>
<td>SNR</td>
<td>4.7208 3.1845 0.6745</td>
<td>70.967 35.484</td>
<td>7.50</td>
<td>214</td>
<td></td>
</tr>
<tr>
<td>STNF-A</td>
<td>4.6288 3.0189 0.6521</td>
<td>64.682 32.341</td>
<td>3.179</td>
<td>460.24</td>
<td></td>
</tr>
<tr>
<td>STNF-SnO(_2)</td>
<td>4.7157 3.0999 0.6573</td>
<td>68.937 34.469</td>
<td>3.563</td>
<td>66370</td>
<td></td>
</tr>
</tbody>
</table>

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The lattice strain has been calculated using a Williamson–Hall (W–H) plot, using the following eqn (3):

$$\frac{\beta \cos \theta}{\lambda} = \frac{1}{D} + \frac{\eta \sin \theta}{\lambda}$$

(3)

where $\eta$ is the strain, and $D$ is the effective crystallite size. The relation between $\beta \cos \theta$ and $\sin \theta$ indicates whether the sample is subjected to compressive stress or tensile strain during the thermal treatment. The W-H plots for the samples are presented in the Fig. SI-4†, it reveals that TNF exhibits compressive stress.55 Whereas, SNR and STNF disclose positive slopes suggesting that both of them undergo tensile strain. The intercepts on the $\beta \cos \theta$ axes give the effective crystallite sizes corresponding to zero strain.51

**UV-vis absorption**

Optical absorption spectra for the nanostructures were recorded and are shown in Fig. 5. The absorption bands of TNF exhibit a peak maxima at 372 nm (3.33 eV). There are no identifications related to impurities/structural defects, and possibly no absorption is observed in the visible region. This strong absorption peak at 372 nm is due to the band-to-band transition.56 Ghosh et al.14 reported that the onset and band edges occurring at 3.17 and 3.02 eV are due to indirect transitions in rutile TiO$_2$, but they are not related to the occupancy of the shallow trap states. In the present study there are no sharp bands observed for SNR and STNF, in contrast with the literature.56,57 The synthesis methods and structural changes can affect the electronic and optical properties of the STNF band edge56,58 and effect coupling59 between the TNF and SNR system.

Introduction of SnO$_2$ into the TiO$_2$ lattice may induce changes in the light absorption properties. STNF exhibits distinct features from TNF and SNR. Since the doping energy level of Sn$^{4+}$ is located at 0.4 eV below the CB of Ti$^{4+}$, it helps to shift the wavelength to lower regions$^{52,56}$ in STNF. The bandgap of STNF eventually falls below the bandgap of anatase TiO$_2$. These changes in the optical bandgap indicate a slight reorganization of the energy band structures$^{60}$ in STNF, compared to the pristine individual systems. Upon the introduction of SnO$_2$ into TiO$_2$, the optical absorption properties of STNF exhibit a blue shift.$^{11,61}$ In addition, the conversion of shape (nanoribbons to nanofibers) lead to a change in the fundamental absorption edge.$^{51}$ Despite the presence of SnO$_2$ in TiO$_2$, negligible effects were also reported in the electronic properties of TiO$_2$ with a lower amount of guest ion introduction.

**Photoluminescence**

The room temperature PL spectra for the electrospun nanostructures were recorded at different excitation wavelengths: $\lambda_{ex1} = 325$, $\lambda_{ex2} = 330$, $\lambda_{ex3} = 350$, $\lambda_{ex4} = 397$ and $\lambda_{ex5} = 540$ nm, presented in Fig. SI-5†. The PL spectra of TNF are shown in Fig. 6, but for better clarity they are plotted in two ranges as 350 to 520 nm (R1) in Fig. 6a and 450 to 800 nm (R2) in Fig. 6b. In R1 ($\lambda_{ex1}$, $\lambda_{ex2}$, $\lambda_{ex3}$ and $\lambda_{ex4}$) four emission peaks $\lambda_{1}^1$, $\lambda_{2}^1$, $\lambda_{3}^1$, and $\lambda_{4}^1$ at 383, 408, 435 and 487 nm respectively are observed. Zhu et al.$^{16}$ reported the energy defect levels within the anatase TiO$_2$ nanocrystals by the optical transient infrared absorption spectroscopy method, and then considered the chemical potentials that enhanced the photo response. The onset of absorption at $\lambda_{1}^1$ corresponds to the bandgap energy of anatase TiO$_2$. Serpone et al.$^{62}$ reported that the band at 383 nm is assigned to the highest energy indirect transition $\chi_{1b}/\Gamma_3$ (where $\chi$ and $\Gamma$ denote the edge and center of the Brillouin zone (BZ)). The
peaks at $P^5_T$ and $P^6_T$ are ascribed to $X_{2b} \rightarrow \Gamma_{1b}$ and $X_{1a} \rightarrow \Gamma_{1b}$ respectively, which are the lowest energy allowed indirect phonon assisted transitions. The emission peak at $P^5_T$ is assigned to the shallow trap level. In $R_3$ ($\lambda_{ex1}$, $\lambda_{ex2}$, $\lambda_{ex3}$, $\lambda_{ex4}$ and $\lambda_{ex5}$, Fig. 6b) two emission peaks $P^5_T$ and $P^2_T$ at 562 nm (2.21 eV) and 585 nm (2.12 eV) respectively are identified. The band in the visible region at $P^5_T$ is attributed to the radiative recombination of self-trapped excitons. The TNF surface exhibits an emission band at $P^5_T$ (~2.2 eV) which is apparently much lower than that of the bandgap energy (3.0 eV for rutile and 3.2 eV for anatase TiO$_2$). These $P^5_T$ and $P^2_T$ peaks belong to shallow traps with $V_{O\prime}$ at 0.99 eV and 1.08 eV below the CB. The shallow traps most likely concern $V_{O\prime}$ at various energies. The green emissions can be described by the following mechanism:

$$\text{TiO}_2 \xrightarrow{\text{hv}} \text{TiO}_2(e^-/h^+) \rightarrow e_{CB}^- + h_{VB}^+$$  \hspace{1cm} (4)

$$V_{O} + e_{CB}^- \rightarrow V_{O\prime} (\text{e}^- \text{trapping in shallow traps})$$  \hspace{1cm} (5)

$$V_{O} \rightarrow h_{VB}^+ \rightarrow V_{O\prime} + \lambda \text{(radiative recombination)}$$  \hspace{1cm} (6)

where $V_{O\prime}$ is an ionized oxygen vacancy level composed to rapidly trap (in tens to hundreds of femtoseconds) a photogenerated CB electron which subsequently interacts with a VB hole (trapped in less than a few picoseconds) either radiatively or non-radiatively. The dominant but not exclusive route for charge carrier recombination in small semiconductor particles is the non-radiative path because of strong coupling of the wave functions of trapped electrons and trapped holes with the lattice phonon.

PL emission spectra of SNR are shown in two ranges, viz. $R_1$ and $R_2$, in Fig. 6c and 6d respectively. Four emission peaks $P^5_T$, $P^2_T$, $P^3_T$ and $P^4_T$ located at 372, 406, 440 and 492 nm can be seen in range $R_1$ (Fig. 6c). It is noteworthy that bulk SnO$_2$ does not show luminescence, but at lower dimensions it does. The peak at $P^5_T$ with violet emission might be due to the near band edge emission. Viana et al. assigned a similar peak of $P^5_T$ to the recombination of electrons from the CB to excitons bound to neutral $D^0_X$.

Kim et al. observed the peak at 416 nm (2.98 eV), but in the present study a broad peak at $P^5_T$ is identified. The origin of this peak is ascribed to $X_{2b}$ resulting from the nanosized SnO$_2$ nanoribbon-like structures. The peak at $P^5_T$ is the blue emission. Kar et al. reported that the SnO$_2$ nanocrystals with larger sizes (26.6 nm) and nearly perfect crystalline structures exhibit stronger violet emission. This $P^5_T$ emission ascribed as a luminescent centre due to electron transitions is mediated by defect levels in the bandgap, such as $V_{O}$ and luminescent centers formed by such interstitial sites or dangling in the presence of SnO$_2$ nanocrystals. The peak at $P^5_T$ is a shallow trap level (~0.8 eV below the CB. Since the energy of the emission band is lower than the bandgap energy of SnO$_2$ ($E_g$ = 3.6 eV), the emission is not due to the direct recombination of a conduction electron in the 4p band of Sn and a hole in the 2p VB of O. The peak at $P^5_T$ is assigned to isolated $V_{O\prime}^+$ centers, which lie at a higher energy than the complex $V_{O\prime}$ center. In range $R_2$ (see Fig. 6d), a broad orange emission peak is identified as $P^6_T$ and $P^5_T$ positioned at 562 and 585 nm. The $P^6_T$ peak is attributed to the radiative recombination of self-trapped excitons, while the other peak at $P^5_T$ was also observed by Gao and Wang. Both of these peaks at $P^5_T$ and $P^6_T$ correspond to oxygen deficiency defects ($V_{O\prime}$ or $S_{ni}$) in the SNR nanoribbons. Viana et al. assigned the peak at 599 nm (2.07 eV) to $V_{O\prime}$. In the present study the peak at $P^6_T$ observed from the SNR nanoribbons is attributed to $V_{O\prime}$.

These midgap $V_{O\prime}$ states were defined by the broad and strong green peaks. The surface states are situated at 2.7 eV below the conduction band minimum (CBM) and 0.9 eV above the valence band maximum (VBM). The observed emission peaks ($P^5_T$ and $P^6_T$) at 2.1 to 2.2 eV are less than the energy gap between the CBM and surface states (~2.7 eV). The electrons from the CB are captured by shallow trap levels below the CB and then recombine with the holes at the surface states (2.7 eV below the CB).

The emission peak intensity with respect to the peak positions are listed (Fig. SI-6 and Table SI-2f). The higher the surface area of the nanostructures is, the greater the number of $V_{O\prime}$ is, which results in decreased PL peak intensities. For better comprehension, the integrated area under the peak plotted against the particular peak position is shown in Fig. 7. $A_{1a}^T$, $A_{2a}^T$, $A_{3a}^T$, $A_{4a}^T$ and $A_{5a}^T$ represent the area under the peaks of $P^1_T$, $P^2_T$, $P^3_T$, $P^4_T$, and $P^5_T$ respectively of TNF (see Fig. 7a). The area of the TNF nanofibers is changed but the position of the PL
peak does not change, indicating that the main PL peak is not the intrinsic feature of TiO₂. These minor changes in the peak positions might be due to the non-uniform distribution of the defect levels at nanodimensions. Similarly, A₁, A₂, A₃, A₄, A₅ and A₆ describe the area under the peak positions at P₁, P₂, P₃, P₄, P₅ and P₆ respectively of SNR, as shown in Fig. 7b. Noticeable from both figures (Fig. 7a and 7b) is the increased peak area at P₅ and P₆ which may result from the increased number of oxygen defects in TNF and SNR. The blue emission is almost zero and only red emission is observed.

Fig. 8a shows the PL emission spectra of STNF, where the peak positions P₁, P₂, P₃, P₄, P₅ and P₆ are at 373, 412, 433, 488, 560 and 586 nm respectively. It is also known that the PL spectra of nanostructures are usually broad and often asymmetric. The degree of crystallinity improves with the increase of the calcination temperature above 400 °C. Hence the calcination temperature and tailored crystallization give rise to modified optical properties in the STNF nanostructures. Since STNF has the higher surface area (see Table 1), VO are easily formed in the nanofibers resulting in structural defects at Ti centres in the basic unit cell of STNF. The peaks at P₁, P₂, P₃, P₄, P₅ and P₆ show little variation when compared to TNF and SNR, which is because SnO₂ is substituted into the TiO₂ system. Interestingly, the peak positions at P₁, P₂, P₃, P₄, P₅ and P₆ are unchanged from TNF and SNR. The origin of the green emission (540–555 nm) in bulk materials is still debatable and some authors attribute it to VO while others attributed it to Ti³⁺. However, it is widely accepted that the origin of the green emission is assigned to the recombination of electrons in the single occupied VO with photoexcited holes. The area under the peaks A₁, A₂, A₃, A₄, A₅ and A₆ positioned at P₁, P₂, P₃, P₄, P₅ and P₆ respectively of STNF is shown in Fig. 8b. As discussed earlier, A₁ and A₂ are dominant for TNF and SNR, whereas A₅ and A₆ are dominant for STNF, i.e. a blue shift has occurred. This blue shift in the peak position suggests that the increased oxygen defect states are starting to form even in the lower wavelength regions.

The proposed band alignment of the nanostructures is shown in Fig. 9. Fig. 9 exhibits six shallow energy bands for TNF and SNR. From Fig. 9 (the TNF part), it is suggested that for the excitations λ₁, λ₂ and λ₃ (3.82, 3.78 and 3.54 eV), electrons from the VB would be excited to the CB and populate all the six bands and recombine with holes at the VB. While for the excitation at λ₄ (3.12 eV), the electrons will not reach even the CB, so there are four bands seen near to the CB. In the case of the λ₅ (2.3 eV) excitation, the energy is 2.29 eV, hence only two bands are observed. From Fig. 9 (the SNR part), it is notable that for the excitations at λ₁ and λ₂, the electron could be excited by more than the SnO₂ bandgap energy (3.6 eV) and at λ₃ (3.54 eV) the electron is close to Eₓ, therefore, all of the six bands will be emitted. Whereas for λ₄ and λ₅, only four and one band will be emitted respectively depending on their corresponding excitation energies. Band alignment of STNF is shown in Fig. 9, and once TiO₂ and SnO₂ contact each other to form a junction, band bending will occur at the interface to reach an equal Fermi
level. When both parts of STNF are excited, electron transfer occurs from the CB of TiO$_2$ to the CB of SnO$_2$ and, conversely, holes transfer from the VB of SnO$_2$ to the VB of TiO$_2$. Thus the $e^-/h^+$ pairs are separated at the interface. The band alignment for STNF is illustrated in Fig. 9. Since the $\lambda_{ex1}$, $\lambda_{ex2}$ and $\lambda_{ex3}$ excitation energies are higher than the bandgap energies of both parts, the electrons from the CB of TNF would be transferred to the all midgap bands of SNR. The populated emission bands are significant at these three excitations. With the excitation energy at $\lambda_{ex3}$, the electrons would be excited up to P$_O^2$ of TNF and transfer to the P$_O^2$, P$_0^3$, P$_0^4$, P$_0^5$ and P$_0^6$ bands of SNR. While at $\lambda_{ex5}$, they can be excited up to P$_O^2$ of TNF and transfer to the P$_O^5$ and P$_O^6$ bands of SNR.

Conclusions
Electrospun SnO$_2$–TiO$_2$ nanofibers were obtained after the calcination of nanoribbon-like structures. The morphologies and dimensions of the nanostructures were observed by SEM. The possible mechanism for the transformation of ribbons into fibers was confirmed and discussed with the literature as support. XRD analysis revealed that both TNF and SNR belong to tetragonal phases and substitutional doping was confirmed. The W–H plots suggested that the lattice has undergone compressive stress/tensile strain. The UV-vis absorption spectra show a band-to-band transition at 372 nm (3.33 eV) for TNF. In the case of SNR and STNF no sharp bands were identified because of the induced structural changes from the synthesis which can affect the electronic and optical properties of the STNF band edge and the effect of coupling between the TNF and SNR system. Therefore, the optical absorption of STNF exhibited a blue shift. The change in morphology leads to a difference in the density of defects which was also observed from the PL spectra. The normalized PL peak exhibits six shallow trap energy levels and their origin is assigned with respect to the excitation wavelength. Band bending was also expected due to the difference in electronegativity of the host and substituent ions, since Sn substitutes for Ti. The integral peak area against the peak position shows that at $\lambda_{ex2}$ and $\lambda_{ex3}$, a green emission is exhibited for TNF and SNR respectively, whereas STNF discloses a blue emission at $\lambda_{ex5}$ and $\lambda_{ex7}$. The proposed band alignment for the electrospun nanostructures of STNF and the possible mechanism for the defect energy bands were elaborated. Apparently, these findings would have great potential in measuring the midgap levels of other semiconductor nanostructures. These investigations would attract much attention and they also require further theoretical explanation of the defect energy states in the STNF system.

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